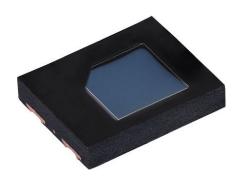


Silicon PIN Photodiode



DESCRIPTION

VEMD5080X01 is a high speed and high sensitive PIN photodiode with enhanced sensitivity for visible light. It is a low profile surface-mount device (SMD) including the chip with a 7.5 mm² sensitive area detecting visible and near infrared radiation.

FEATURES

- Package type: surface-mount
- · Package form: top view
- Dimensions (L x W x H in mm): 5 x 4 x 0.9
- Radiant sensitive area (in mm²): 7.5
- AEC-Q101 qualified
- Enhanced sensitivity for visible light
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 65^{\circ}$
- Floor life: 72 h, MSL 4, according to J-STD-020
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



AUTOMOTIVE



APPLICATIONS

· High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I _{ra} (μΑ)	φ (°)	λ _{0.1} (nm)	
VEMD5080X01	45	± 65	350 to 1100	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VEMD5080X01	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Top view		
VEMD5080X01-GS15	Tape and reel	MOQ: 5000 pcs, 5000 pcs/reel	Top view		

Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	20	V	
Power dissipation	T _{amb} ≤ 25 °C	P_V	215	mW	
Junction temperature		Tj	110	°C	
Operating temperature range		T _{amb}	-40 to +110	°C	
Storage temperature range		T _{stg}	-40 to +110	°C	
Soldering temperature	According to reflow solder profile Fig. 8	T_{sd}	260	°C	
Thermal resistance junction to ambient		R_{thJA}	350	K/W	
ESD safety HBM	\pm 2000 V, 1.5 k Ω , 100 pF, 3 pulses	ESD _{HBM}	≥ 2	kV	



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BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA	V_{F}	-	0.9	1.3	V
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	20	-	=	V
Reverse dark current	V _R = 10 V, E = 0	I _{ro}	-	0.2	10	nA
Diode capacitance	$V_R = 0 V, f = 1 MHz, E = 0$	C _D	-	80	-	pF
	$V_R = 3 V, f = 1 MHz, E = 0$	C _D	-	30	40	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo	-	320	-	mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{Vo}	-	-3.0	-	mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I _k	-	45	-	μΑ
Temperature coefficient of Ik	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{lk}	-	0.1	-	%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, V_R = 5 \text{ V}$	I _{ra,IR}	33	45	53	μΑ
	$E_e = 0.2 \text{ mW/cm}^2, \lambda = 525 \text{ nm}, V_R = 5 \text{ V}$	I _{ra,G}	3.1	5.0	6.6	μA
	$E_e = 1 \text{ mW/cm}^2, \lambda = 460 \text{ nm}, V_R = 5 \text{ V}$	I _{ra,B}	13.5	18	25	μA
Angle of half sensitivity		φ	-	± 65	-	0
Wavelength of peak sensitivity		λ_{p}	-	950	=	nm
Range of spectral bandwidth		λ _{0.1}	-	350 to 1100	=	nm
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 830 \text{ nm}$	t _r	-	70	=	ns
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 830 \text{ nm}$	t _f	-	70	=	ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

Basic characteristics graphs to be extended to 110 °C ambient temperatures where applicable.

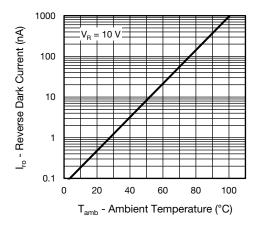


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

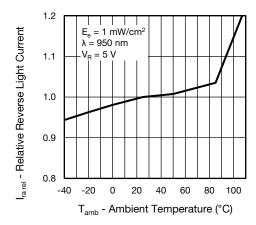


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

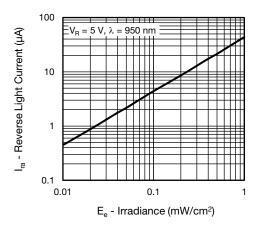


Fig. 3 - Reverse Light Current vs. Irradiance

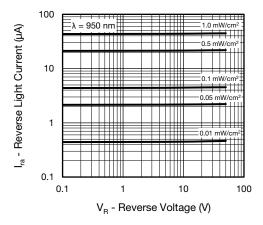


Fig. 4 - Reverse Light Current vs. Reverse Voltage

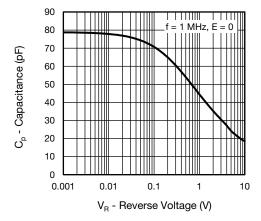


Fig. 5 - Diode Capacitance vs. Reverse Voltage

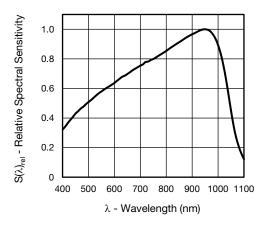


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

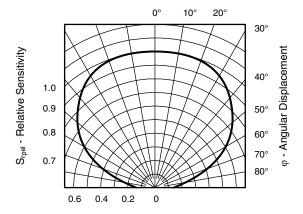
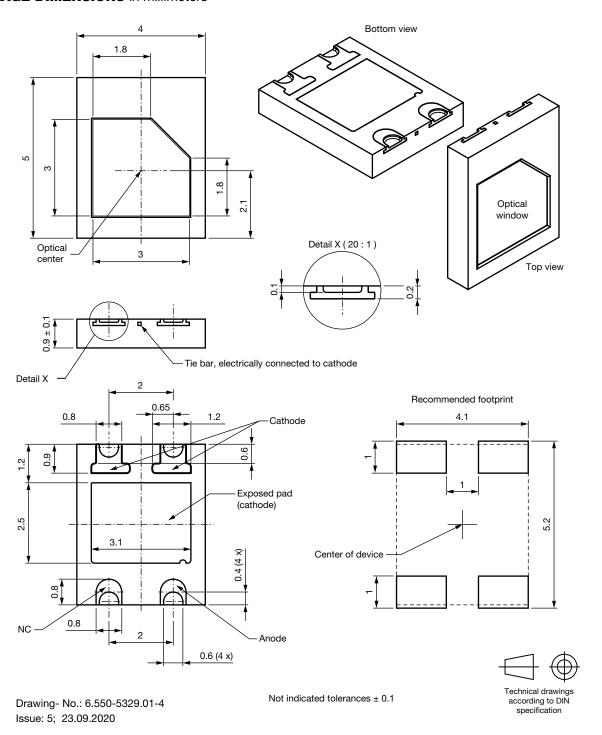


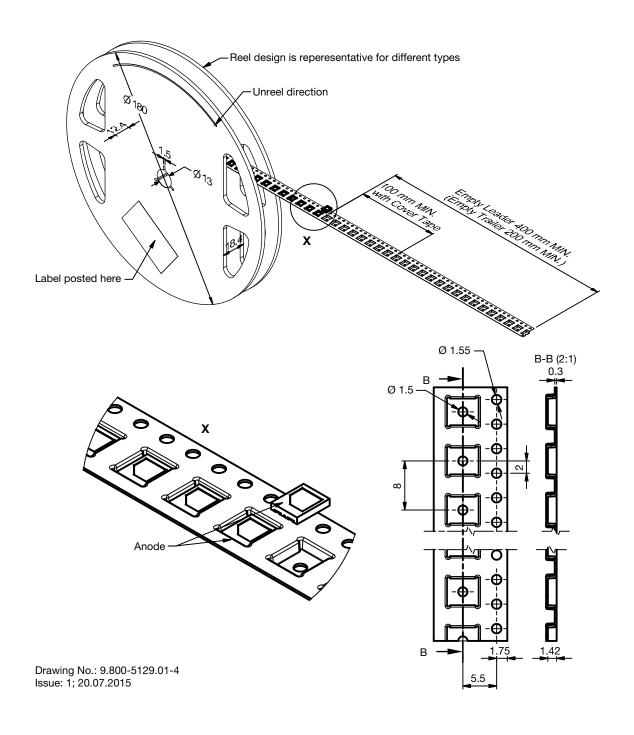
Fig. 7 - Relative Sensitivity vs. Angular Displacement



PACKAGE DIMENSIONS in millimeters



TAPE AND REEL DIMENSIONS in millimeters





SOLDER PROFILE

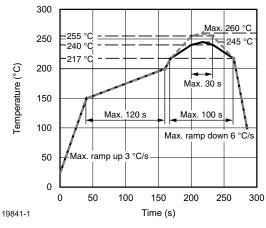


Fig. 8 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020D

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 4

Floor life: 72 h

Conditions: T_{amb} < 30 °C, RH < 60 %

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 %

or

96 h at 60 °C (+ 5 °C), RH < 5 %



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